

UP04316

Silicon NPN epitaxial planar transistor (Tr1)
 Silicon PNP epitaxial planar transistor (Tr2)

For switching
 For digital circuit

■ Features

- Two elements incorporated into one package (Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

■ Basic Part Number of Element

- UNR1216 (UN1216) + UNR1116 (UN1116)

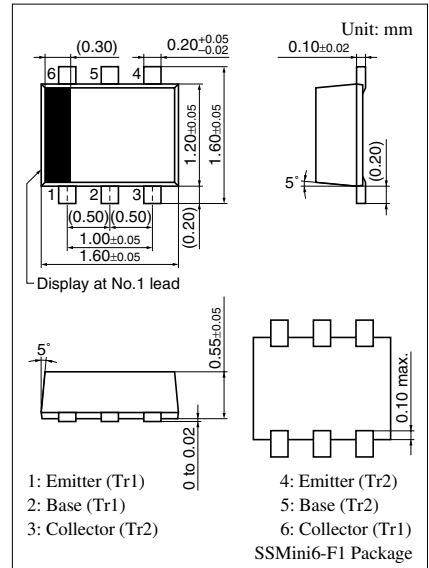
■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| | Parameter | Symbol | Rating | Unit |
|---------|------------------------------|-----------|-------------|------------------|
| Tr1 | Collector to base voltage | V_{CBO} | 50 | V |
| | Collector to emitter voltage | V_{CEO} | 50 | V |
| | Collector current | I_C | 100 | mA |
| Tr2 | Collector to base voltage | V_{CBO} | -50 | V |
| | Collector to emitter voltage | V_{CEO} | -50 | V |
| | Collector current | I_C | -100 | mA |
| Overall | Total power dissipation | P_T | 125 | mW |
| | Junction temperature | T_j | 125 | $^\circ\text{C}$ |
| | Storage temperature | T_{stg} | -55 to +125 | $^\circ\text{C}$ |

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

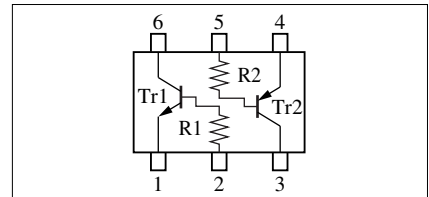
- Tr1

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---|---------------|--|------|-----|------|------------------|
| Collector to base voltage | V_{CBO} | $I_C = 10 \mu\text{A}, I_E = 0$ | 50 | | | V |
| Collector to emitter voltage | V_{CEO} | $I_C = 2 \text{ mA}, I_B = 0$ | 50 | | | V |
| Collector cutoff current | I_{CBO} | $V_{CB} = 50 \text{ V}, I_E = 0$ | | | 0.1 | μA |
| | I_{CEO} | $V_{CE} = 50 \text{ V}, I_B = 0$ | | | 0.5 | |
| Emitter cutoff current | I_{EBO} | $V_{EB} = 6 \text{ V}, I_C = 0$ | | | 0.01 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$ | 160 | | 460 | |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | $I_C = 10 \text{ mA}, I_B = 0.3 \text{ mA}$ | | | 0.25 | V |
| High-level output voltage | V_{OH} | $V_{CC} = 5 \text{ V}, V_B = 0.5 \text{ V}, R_L = 1 \text{ k}\Omega$ | 4.9 | | | V |
| Low-level output voltage | V_{OL} | $V_{CC} = 5 \text{ V}, V_B = 2.5 \text{ V}, R_L = 1 \text{ k}\Omega$ | | | 0.2 | V |
| Input resistance | R_1 | | -30% | 4.7 | +30% | $\text{k}\Omega$ |
| Transition frequency | f_T | $V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$ | | 150 | | MHz |



Marking Symbol: 7U

Internal Connection



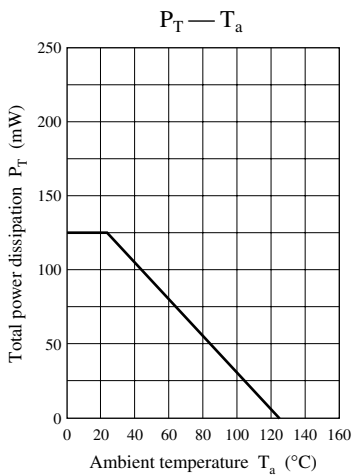
Note) The part number in the parenthesis shows conventional part number.

■ Electrical Characteristics (continued) $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

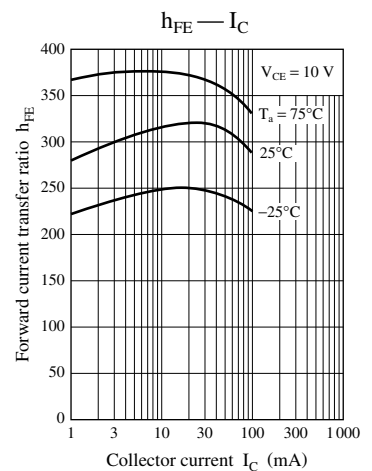
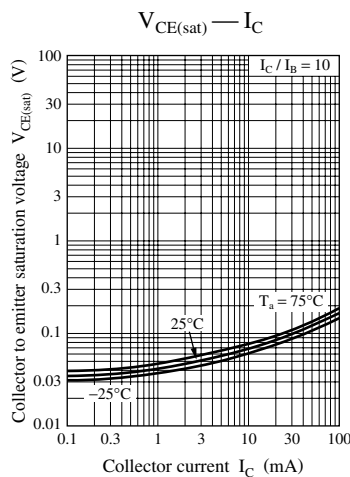
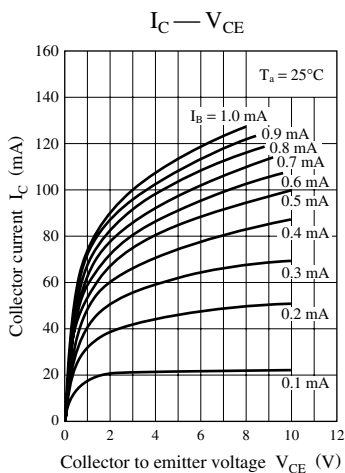
• Tr2

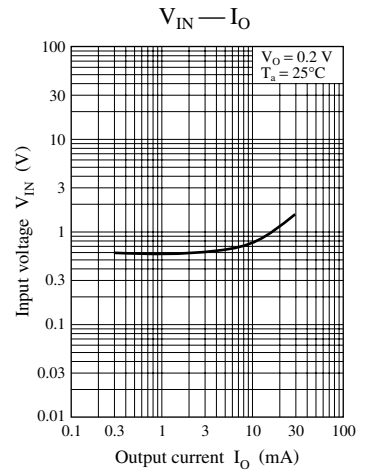
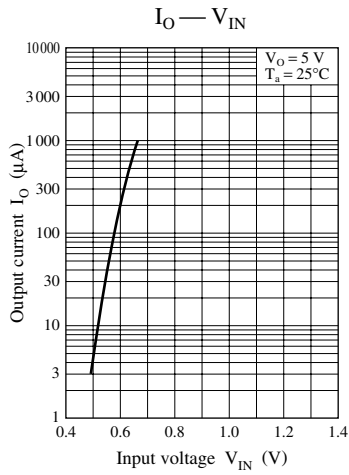
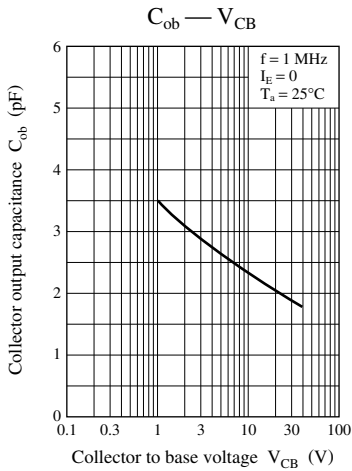
| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---|---------------|--|------|-----|-------|---------------|
| Collector to base voltage | V_{CBO} | $I_C = -10 \mu\text{A}, I_E = 0$ | -50 | | | V |
| Collector to emitter voltage | V_{CEO} | $I_C = -2 \text{ mA}, I_B = 0$ | -50 | | | V |
| Collector cutoff current | I_{CBO} | $V_{CB} = -50 \text{ V}, I_E = 0$ | | | -0.1 | μA |
| | I_{CEO} | $V_{CE} = -50 \text{ V}, I_B = 0$ | | | -0.5 | |
| Emitter cutoff current | I_{EBO} | $V_{EB} = -6 \text{ V}, I_C = 0$ | | | -0.5 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = -10 \text{ V}, I_C = -5 \text{ mA}$ | 160 | | 460 | |
| Collector to emitter saturation voltage | $V_{CE(sat)}$ | $I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$ | | | -0.25 | V |
| High-level output voltage | V_{OH} | $V_{CC} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$ | -4.9 | | | V |
| Low-level output voltage | V_{OL} | $V_{CC} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$ | | | -0.2 | V |
| Input resistance | R_1 | | -30% | 4.7 | +30% | k Ω |
| Transition frequency | f_T | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$ | | 80 | | MHz |

Common characteristics chart

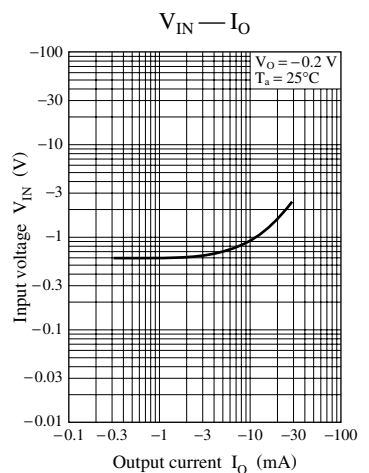
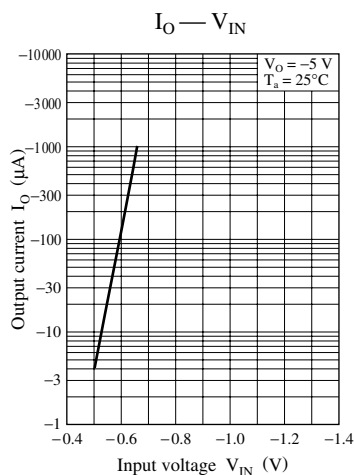
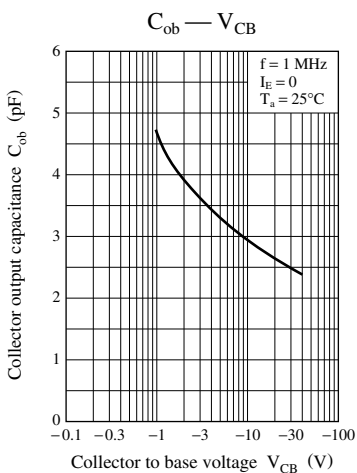
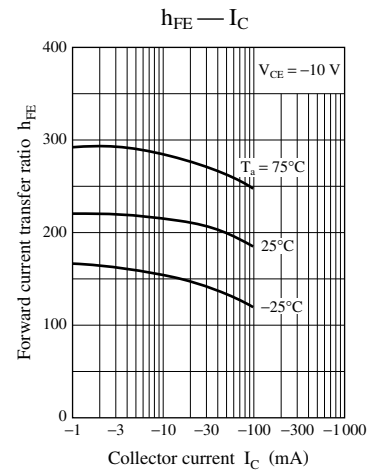
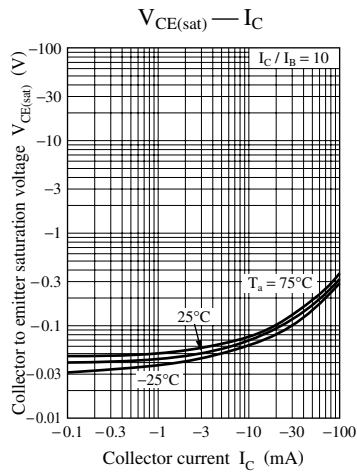
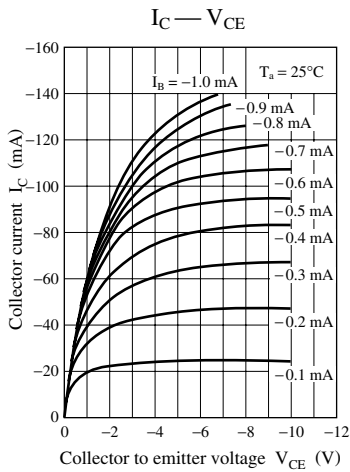


Characteristics chart of Tr1





Characteristics chart of Tr2



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